

**AMENDMENTS TO THE SPECIFICATION**

Please amend the Title of the above-identified application to read “HETEROJUNCTION BIPOLAR TRANSISTOR WITH A BASE LAYER THAT CONTAINS BISMUTH”.

In addition, in accordance with 37 § CFR 1.121(b)(2), please amend the specification as set forth in the attached Substitute Specification. Marked-up (redlined) and clean versions of the Substitute Specification have also been attached in accordance with 37 CFR § 1.125(c).